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HSQ Resist - Datasheet

Features

Film Thickness:

10 – 850 nm

Excellent line edge
roughness
High Resolution

Customisable solutions

Introduction

Hydrogen silsesquioxane (HSQ), with a chemical formula of HSiOx, is a high purity, silsesquioxane-based semiconductor grade polymer applicable as a negative tone resist for electron beam patterns, EUV, nanoimprint lithography and Step and Flash Imprint Lithography (SFIL). It is readily soluble in non-polar organic solvents like methyl isobutylketone (MIBK), methyl siloxane and toluene for thin-film fabrication. Depending on the film thickness, a dense pattern with sub-10 nm half pitch can be achieved. The resist can be supplied in liquid form, powder form or in a self-dilution kit.

Processing Conditions

Substrate Preparation

HSQ can be spun on a range of substrates without adhesion layers. Ensure that the substrate is clean and dry. Substrate cleaning can be performed using solvents, O_2 Plasma and O_3 .

Powder Dilution

If your HSQ has been supplied in powder form, dilution needs to be performed prior to substrate coating. Dilution should be performed in a clean environment with fume extraction. Mix the appropriate amount of HSQ with MIBK to obtain your desired concentration by weight. Filter the resulting solution using a 0.2µm inline filter with a syringe. A separate dilution procedure document is available.

Only use MIBK provided by EM Resist. Leave the solvent bottle open for as little time as possible and tightly close the lid after use. Limit the number of times the solvent bottle is opened and do not use MIBK after 3 months of first opening. EM Resist are not liable for any mishandling of powder HSQ, incorrect use of MIBK provided by us, or use of MIBK from other suppliers. If alternative MIBK is sourced by the end user, ensure it is HPLC grade (>99.5%) or better and <0.02% water content (check the batch's CoA).



Coat

EM Resist HSQ products are coated on the substrate using a spin coating process. The film thickness spin curves of representative HSQ solutions are displayed below. These provide the information required to select the HSQ dilution for the desired film thickness and spin speed.

Ensure that refrigerated resist solutions are allowed to equilibrate to room temperature prior to opening. Failure to do so will result in water condensation inside the bottle, which may spoil the resist.

Dispense the solution onto the substrate. Use a 2 second ramp time to ramp up to the desired spin speed then hold for 40 seconds.

Soft Bake

Hotplate: 150°C for 120 s

Exposure

Electron beam lithography: Dose $400 - 700\mu\text{C/cm}^2$ depending on electron source, equipment, exposure energy and developer used.

Post Exposure Bake

A post exposure bake at 350°C or higher temperature in N₂ can enhance the contrast properties of the film.

Develop

HSQ films can be developed using any standard aqueous base developer such as 0.26N TMAH for 70 seconds.

Rinse and Dry

Upon completion of the development process, the resist should be rinsed with flowing DI water to prevent scumming. Substrates can be spin dried at 3000rpm for 20s or blow dried with a dry, inert gas (typically N_2).

Removal techniques

After exposing HSQ resist, the film is converted to silicon dioxide, therefore HSQ can be removed with hydrofluoric acid (HF) or buffered oxide etch (BOE).

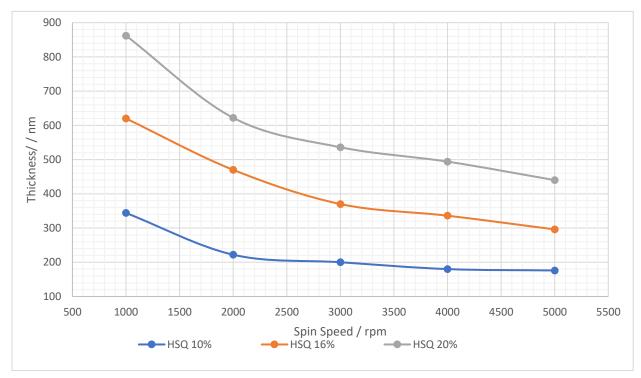
Shelf-life and Storage

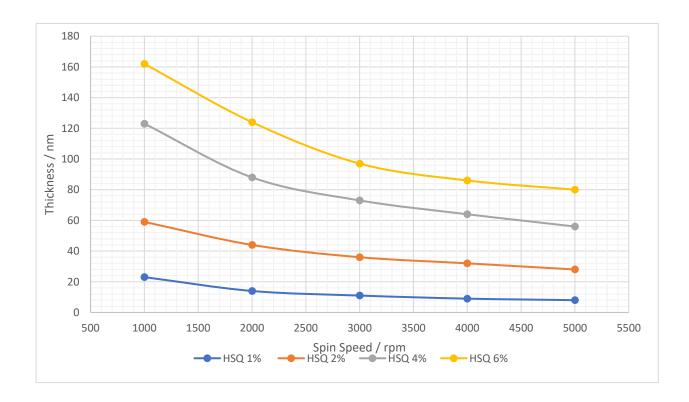
In powder form, HSQ can be kept for at least 1 year at room temperature providing it is stored under dry ambient conditions in the absence of light, and ideally in a vacuum desiccator. Do not store HSQ solid or liquid in glass containers as this will cause irreversible gelation of the product.

When in solution, HSQ has a shelf life of 3 months when stored below 5°C.

Spin Curves

The spin curves shown below are for HSQ solutions in MIBK solvent. They show the film thickness that is obtained based on the spin speed that is selected. This data provides approximate information to allow for the selection of the correct product/dilution for your application and desired film thickness. Actual results will vary based on equipment, environment, process conditions and application. Additional dilutions are available upon request.





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